Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L9	120	(257/059 or 257/72 or 257/765 or 257/771).ccls. and ((gate or drain or source or electrode) same ((aluminum or al) and (titanium or ti) and (titanium adj nitride) and (TiN)))	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/12/12 11:10
L10	159	(349/139 or 349/147 or 349/148).ccls. and ((gate or drain or source or electrode) same ((aluminum or al) and (titanium or ti) and ((titanium adj nitride) or (TiN)))) and @ad<"20030313"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/12/12 11:14
L11	2251	(semiconductor or TFT or display) and ((gate or drain or source or electrode) with (Ti and TiN and (Al or Aluminum))) and @ad<"20030313"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/12/12 11:44
L12	672	(semiconductor or TFT or display) and ((gate or drain or source or electrode) with (Ti and TiN and (Al or Aluminum))) and @ad<"20030313" and ((preven$5 or barrier) with (TiN or (titanium adj nitride)))	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/12/12 11:45
S18	475	(semiconductor or TFT or display) and ((gate or drain or source or electrode) with (Ti and TiN and (Al or Aluminum))) and @ad<"20030312" and ((preven$5 or barrier) with (TiN or (titanium adj nitride))) not S15	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/12/12 11:45
L13	525	(TFT or display or LCD) and ((gate or drain or source or electrode) with (Ti and TiN and (Al or Aluminum))) and @ad<"20030313" and ((drain near3 electrode) with (gate near3 electrode))	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/12/12 11:57